

**2SD2607**

- 1) Darlington connection for high DC current gain.
- 2) Built-in resistor between base and emitter.
- 3) Built-in damper diode.
- 4) Complements the 2SB1668.

| Parameter                 | Symbol    | Limits          | Unit                           |
|---------------------------|-----------|-----------------|--------------------------------|
| Collector-base voltage    | $V_{CB0}$ | 100             | V                              |
| Collector-emitter voltage | $V_{CE0}$ | 100             | V                              |
| Emitter-base voltage      | $V_{EB0}$ | 7               | V                              |
| Collector current         | $I_C$     | 8               | A (DC)                         |
|                           |           | 10              | A (Pulse) *                    |
| Power dissipation         | $P_C$     | 2               | W                              |
|                           |           | 30              | W ( $T_C = 25^\circ\text{C}$ ) |
| Junction temperature      | $T_J$     | 150             | $^\circ\text{C}$               |
| Storage temperature       | $T_{Stg}$ | $-55 \sim +150$ | $^\circ\text{C}$               |

10.0

15.0

12.0

8.0

5.0

1.2

1.3

0.8

2.54

2.54

3.2

4.5

2.8

0.75

2.6

(1)(2)(3)

1 2 3

1) Base(Gate)  
2) Collector(Drain)  
3) Emitter(Source)

ROHM : TO-220FN

|                              |          |
|------------------------------|----------|
| Type                         | 2SD2607  |
| Package                      | TO-220FN |
| h <sub>FE</sub>              | 1k~20k   |
| Code                         | -        |
| Basic ordering unit (pieces) | 500      |

$R1 \cong 5k\Omega$   
 $R2 \cong 300k\Omega$

B : Base  
 C : Collector  
 E : Emitter

| Parameter                            | Symbol        | Min. | Typ. | Max.  | Unit    | Conditions                            |
|--------------------------------------|---------------|------|------|-------|---------|---------------------------------------|
| Collector-base breakdown voltage     | $BV_{CBO}$    | 100  | -    | -     | V       | $I_C = 50\mu A$                       |
| Collector-emitter breakdown voltage  | $BV_{CEO}$    | 100  | -    | -     | V       | $I_C = 5mA$                           |
| Collector cutoff current             | $I_{CBO}$     | -    | -    | 10    | $\mu A$ | $V_{CB} = 100V$                       |
| Emitter cutoff current               | $I_{EBO}$     | -    | -    | 3     | $mA$    | $V_{EB} = 5V$                         |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | -    | -    | 1.5   | V       | $I_C/I_E = 3A/6mA$                    |
| DC current transfer ratio            | $h_{FE}$      | 1000 | -    | 20000 | -       | $V_{CE}/I_C = 3V/2A$                  |
| Transition frequency                 | $f_T$         | -    | 40   | -     | MHz     | $V_{CE} = 5V, I_E = -0.2A, f = 10MHz$ |
| Output capacitance                   | $C_{ob}$      | -    | 50   | -     | pF      | $V_{CB} = 10V, I_E = 0A, f = 1MHz$    |

\*2 Transition frequency of the device.